



# TSD882S

Low V<sub>ce(sat)</sub> NPN Transistor

TO-92



SOT-89



Pin assignment:

TO-92

1. Emitter
2. Collector
3. Base

SOT-89

1. Base
2. Collector
3. Emitter

**BV<sub>CEO</sub> = 50V**

**I<sub>c</sub> = 3A**

**V<sub>CE (SAT)</sub> = 0.3V(typ.) @I<sub>c</sub> / I<sub>b</sub> = 2A / 20mA**

## Features

- ❖ Low V<sub>CE (SAT)</sub>.
- ❖ Excellent DC current gain characteristics

## Structure

- ❖ Epitaxial planar type.
- ❖ Complimentary to TSB772S

## Ordering Information

Part No.	Packing	Package
TSD882SCT	Bulk Pack	TO-92
TSD882SCY	Tape & Reel	SOT-89

## Absolute Maximum Rating (Ta = 25 °C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50V	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50V	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current	DC	I <sub>c</sub>	A
	Pulse	7 (note 1)	
Collector Power Dissipation	TO-92	P <sub>D</sub>	0.75
	SOT-89		0.50
Operating Junction Temperature	T <sub>J</sub>	+150	°C
Operating Junction and Storage Temperature Range	T <sub>STG</sub>	- 55 to +150	°C

Note: 1. Single pulse, P<sub>w</sub> = 350μS, Duty <= 2%

## Electrical Characteristics

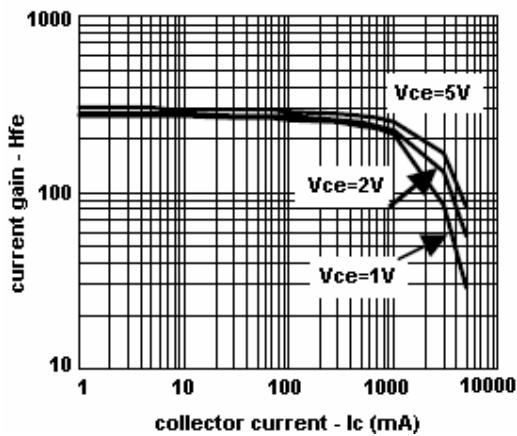
Ta = 25 °C unless otherwise noted

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Static</b>						
Collector-Base Voltage	I <sub>C</sub> = 50μA, I <sub>E</sub> = 0	BV <sub>CBO</sub>	50	--	--	V
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 1mA, I <sub>B</sub> = 0	BV <sub>CEO</sub>	50	--	--	V
Emitter-Base Breakdown Voltage	I <sub>E</sub> = 50μA, I <sub>C</sub> = 0	BV <sub>EBO</sub>	5	--	--	V
Collector Cutoff Current	V <sub>CB</sub> = 40V, I <sub>E</sub> = 0	I <sub>CBO</sub>	--	--	1	uA
Emitter Cutoff Current	V <sub>EB</sub> = 4V, I <sub>C</sub> = 0	I <sub>EBO</sub>	--	--	--	uA
Collector-Emitter Saturation Voltage	I <sub>C</sub> / I <sub>B</sub> = 2.0A / 0.2A	V <sub>CE(SAT)</sub>	--	0.3	0.5	V
DC Current Transfer Ratio	V <sub>CE</sub> = 2V, I <sub>C</sub> = 1A	h <sub>FE</sub>	160	--	500	
Transition Frequency	V <sub>CE</sub> = 5V, I <sub>C</sub> = 100mA, f = 100MHz	f <sub>T</sub>	--	90	--	MHz
Output Capacitance	V <sub>CB</sub> = 10V, f=1MHz	C <sub>ob</sub>		45	--	pF

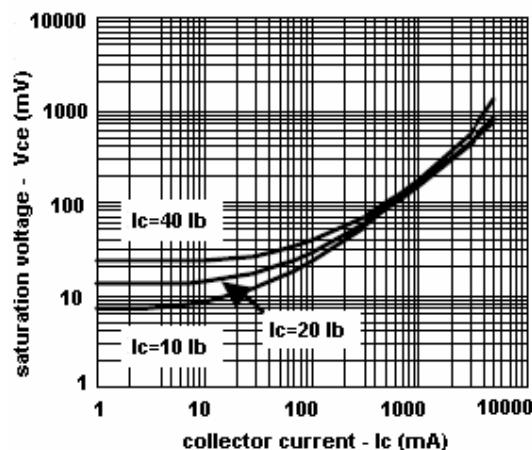
Note : pulse test: pulse width <=380μS, duty cycle <=2%

## Electrical Characteristics Curve

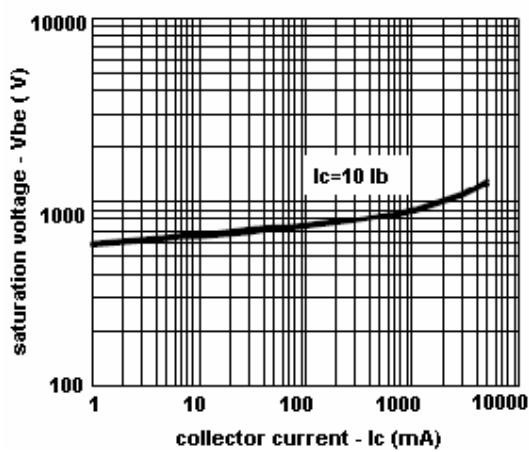
**Figure 1. Current Gain vs Collector Current**



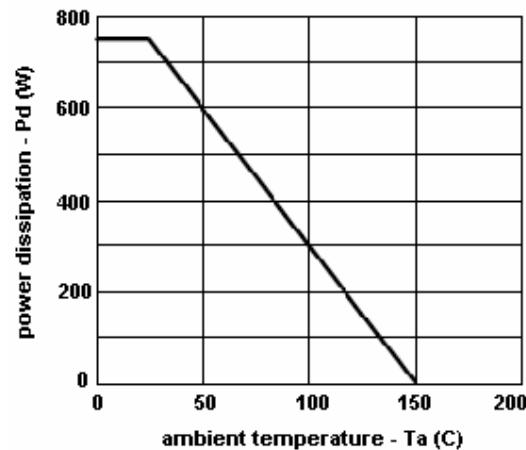
**Figure 2. Saturation Voltage vs Collector Current**



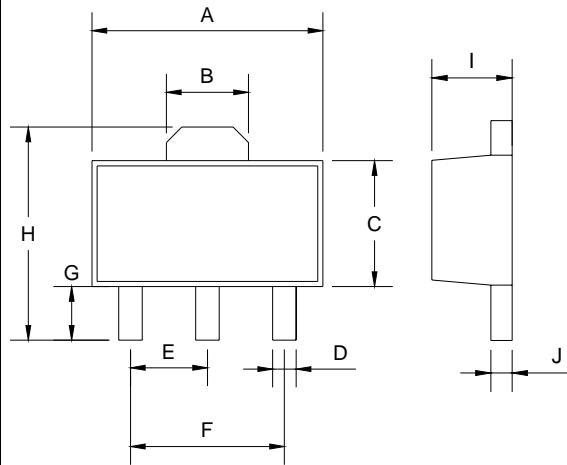
**Figure 3. Saturation Voltage vs Collector Current**



**Figure 4. Power Derating Curves**

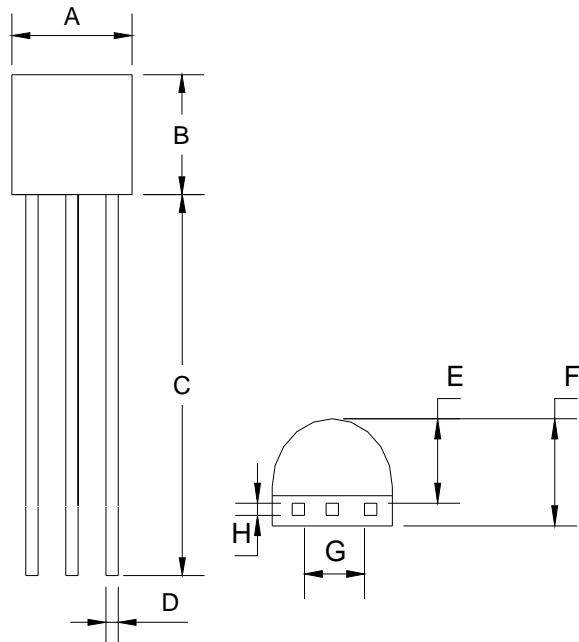


## SOT-89 Mechanical Drawing



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.40	4.60	0.173	0.181
B	1.50	1.7	0.059	0.070
C	2.30	2.60	0.090	0.102
D	0.40	0.52	0.016	0.020
E	1.50	1.50	0.059	0.059
F	3.00	3.00	0.118	0.118
G	0.89	1.20	0.035	0.047
H	4.05	4.25	0.159	0.167
I	1.4	1.6	0.055	0.068
J	0.35	0.44	0.014	0.017

## TO-92 Mechanical Drawing



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.70	0.169	0.185
B	4.30	4.70	0.169	0.185
C	14.30(typ)		0.563(typ)	
D	0.43	0.49	0.017	0.019
E	2.19	2.81	0.086	0.111
F	3.30	3.70	0.130	0.146
G	2.42	2.66	0.095	0.105
H	0.37	0.43	0.015	0.017